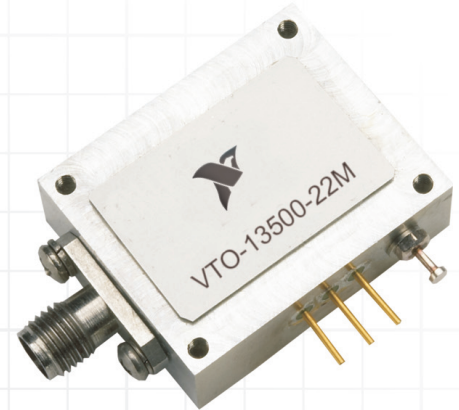


# 12 to 15 GHz VOLTAGE TUNED OSCILLATOR

VTO-13500-22M



### Overview:

NI's VTO-13500-22M is a low-noise fundamental voltage-controlled source, which covers 12 to 15 GHz and can be used as a clock in high-speed systems or as a local oscillator or transmitter oscillator in high-frequency communications and radar systems. This low-noise source uses a high-performance, low-noise silicon bi-polar junction transistor (Si BJT) in conjunction with a hyper-abrupt varactor diode to tune over 3 GHz of frequency range in Ku-band.

A GaAs MMIC buffer amplifier is used to provide the necessary power output and load isolation of the oscillators.

### Features:

- Operating frequency 12 to 15 GHz
- Output power 10 dBm min.
- Phase noise < -90 dBc/Hc @ 100 kHz
- Low power consumption
- Modulation sensitivity 100 to 250 MHz/V
- Tuning voltage 0 to 20 V

### Applications:

- Low-noise X-band source
- Radars/Communications

## Specifications

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	UNITS	RATING
Positive Supply Voltage	V	+6
Negative Supply Voltage	V	-12
Tuning Voltage	V	0 to +20
Operating Temperature	C	-10° to +85°
Storage Temperature	C	-40° to +125°

### ELECTRICAL SPECIFICATIONS (measured at 0° to +70°)

PARAMETER	UNITS	MIN.	TYP.	MAX.
Center Frequency $f_0$	GHz	12		15
Vt @ 12 GHz	V	0		
Vt @ 15 GHz	V			20

### ELECTRICAL SPECIFICATIONS (continued)

PARAMETER	UNITS	MIN.	TYP.	MAX.
Output Power (50 ohms load)	dBm	10	12	16
Tuning Sensitivity	MHz/V	100		250
Tuning Sensitivity Ratio			2:1	
Modulation Bandwidth	MHz	20		
Output Return Loss	dB	10	12	
Second Harmonic (below carrier)	dBc			-20
Third Harmonic (below carrier)	dBc			-20
Spurious Output (below carrier)	dBc			-60
Phase Noise @ 100 kHz from $f_0$	dBc/Hz		-90	-85
Phase Noise @ 10 MHz from $f_0$	dBc/Hz			-125
Freq. Drift over Temp.	MHz			100

